



America Semiconductor

Silicon Bridge Rectifier

BR36 thru BR310

$V_{RRM} = 50\text{ V} - 1000\text{ V}$

$I_F = 3\text{ A}$

Features

- Types up to 1000 V V_{RRM}
- Ideal for printed circuit board
- Low forward voltage drop
- High temperature soldering guaranteed: 250°C/ 10 seconds, 0.375" lead length
- Low leakage current

BR-3 Package



Mechanical Data

Case: Molded plastic body

Polarity: Marked on body

Mounting position: Any

Mounting: Hole for number 6 screw

Maximum ratings, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	BR36	BR38	BR310	Unit
Repetitive peak reverse voltage	V_{RRM}		600	800	1000	V
RMS reverse voltage	V_{RMS}		420	560	700	V
DC blocking voltage	V_{DC}		600	800	1000	V
Continuous forward current	I_F	$T_C \leq 50\text{ °C}$	3	3	3	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ °C}$, $t_p = 8.3\text{ ms}$	50	50	50	A
Operating temperature	T_j		-65 to 125	-65 to 125	-65 to 125	°C
Storage temperature	T_{stg}		-65 to 150	-65 to 150	-65 to 150	°C

Electrical characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	BR36	BR38	BR310	Unit
Diode forward voltage	V_F	$I_F = 1.5\text{ A}$, $T_j = 25\text{ °C}$	1	1	1	V
Reverse current	I_R	$V_R = 50\text{ V}$, $T_j = 25\text{ °C}$	10	10	10	μA
		$V_R = 50\text{ V}$, $T_j = 100\text{ °C}$	100	100	100	





FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

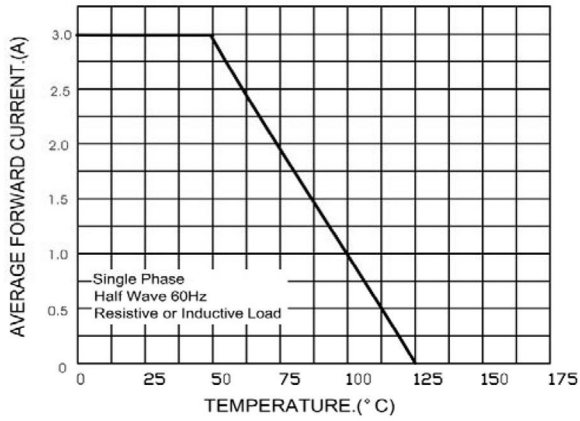


FIG.2-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

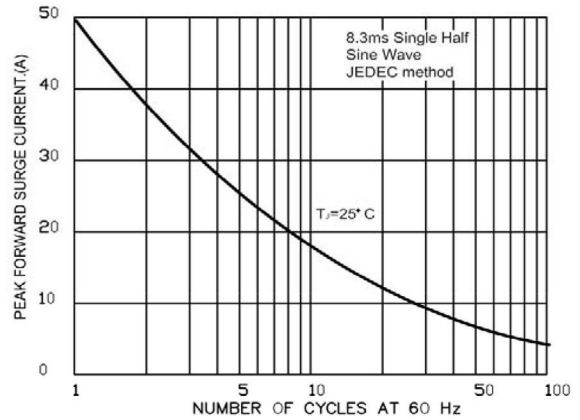


FIG.3-TYPICAL FORWARD CHARACTERISTICS

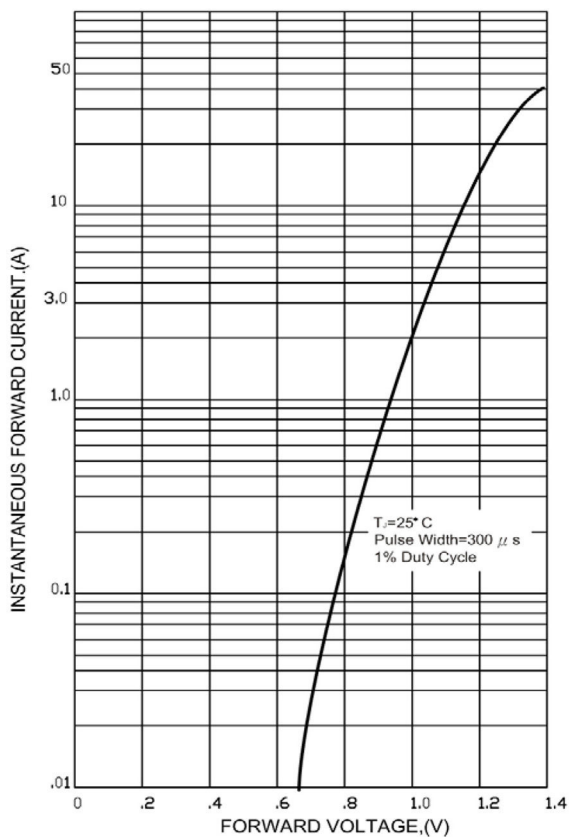
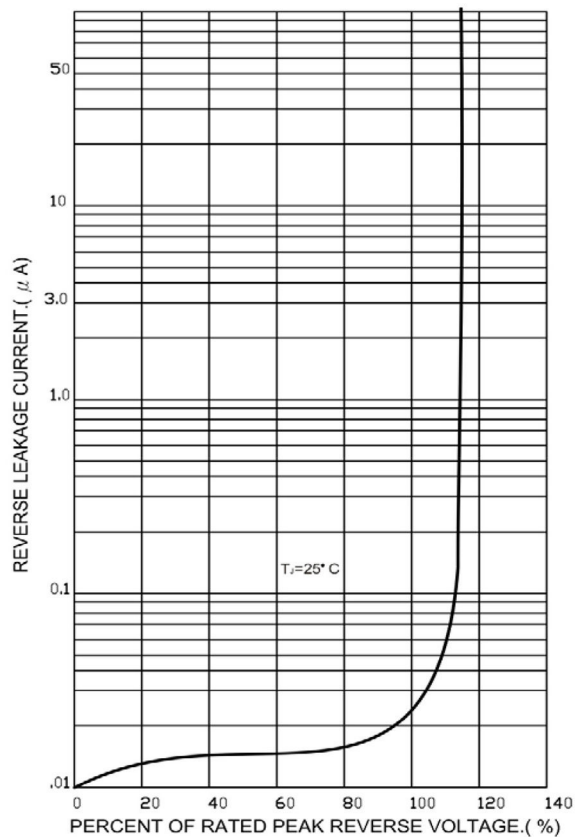


FIG.4-TYPICAL REVERSE CHARACTERISTICS





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.